



S2AF THRU S2MF

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Ampere

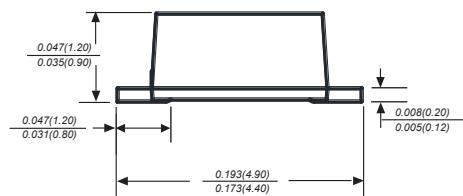
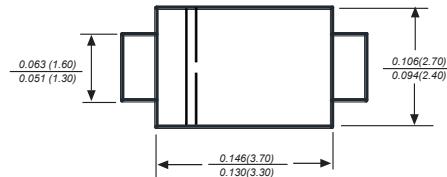
SURFACE MOUNT GENERAL RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Idea for printed circuit board
- ◆ Open Junction chip
- ◆ Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed 250°C/10 seconds at terminals

SMAF

ROHS
COMPLIANT



Mechanical Data

Case*: SMAF molded plastic body

Terminals*: Solderable per MIL-STD-750, Method 2026

Polarity*: Polarity symbol marking on body

Mounting Position*: Any

Weight : 0.00095ounce, 0.027grams

Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	MDD S2AF	MDD S2BF	MDD S2DF	MDD S2GF	MDD S2JF	MDD S2KF	MDD S2MF	UNITS
Marking Code									
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at TL=125°C	I _(AV)					2.0			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}					50			A
Maximum instantaneous forward voltage at 2.0A	V _F					1.10			V
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =125°C	I _R				5.0	100			uA
Typical junction capacitance (NOTE 1)	C _J				22.0				pF
Typical thermal resistance (NOTE 2)	R _{θJA} R _{θJC}				65.0	20.0			°C/W
Operating junction and storage temperature range	T _{J,T_{STG}}				-55 to +150				°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 2.0"x2.0"(5.0x5.0cm) copper pad areas



Typical Characteristics

Fig.1 Forward Current Derating Curve

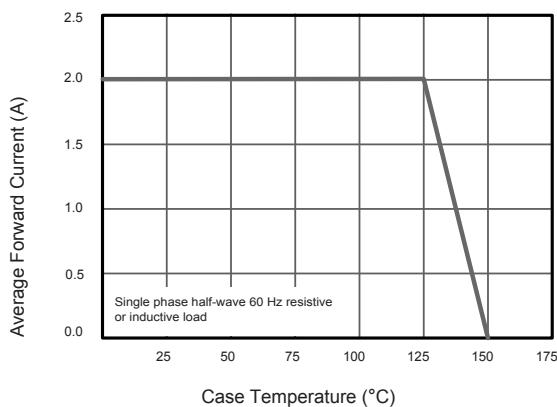


Fig.2 Typical Instantaneous Reverse Characteristics

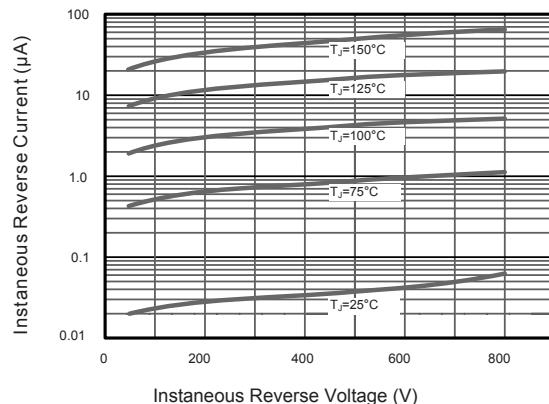


Fig.3 Typical Forward Characteristic

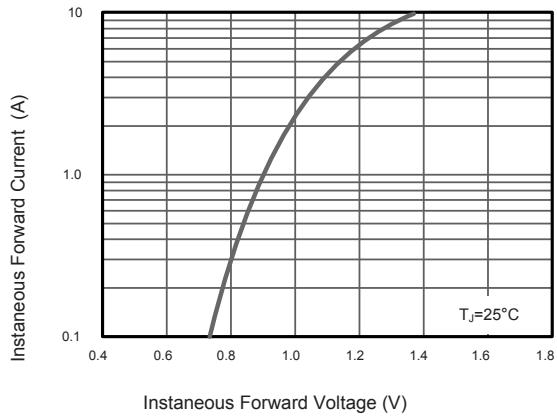


Fig.4 Typical Junction Capacitance

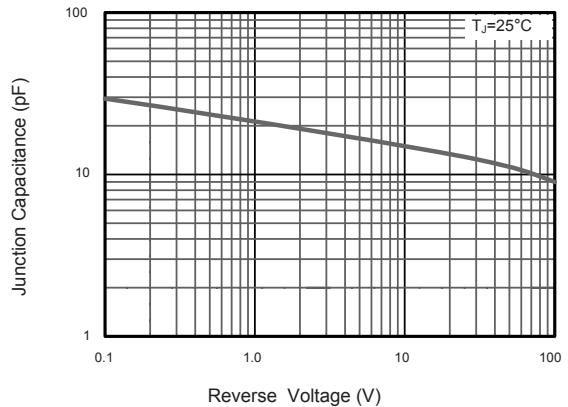
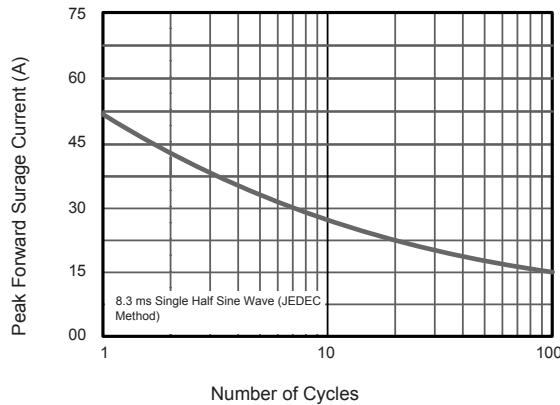


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



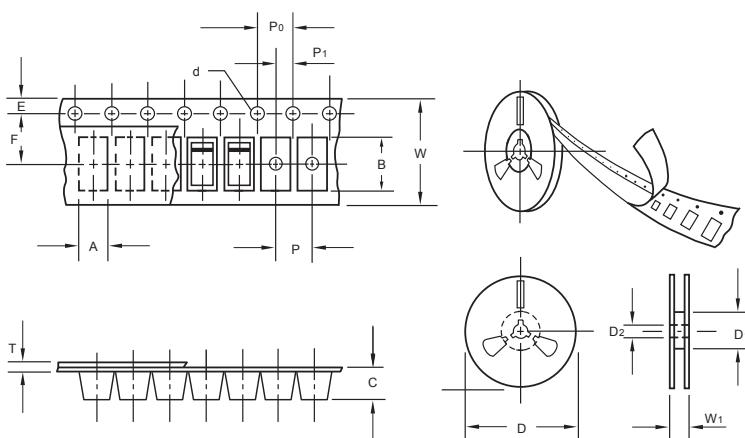
The curve above is for reference only.



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Packing information



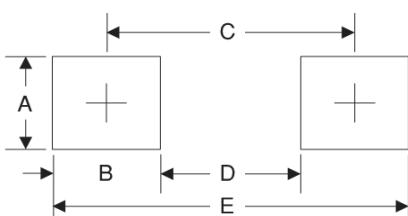
Item	Symbol	Tolerance	SMF
Carrier width	A	0.1	2.80
Carrier length	B	0.1	4.75
Carrier depth	C	0.1	1.42
Sprocket hole	d	0.05	1.50
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D ₁	min	54.40
Feed hole diameter	D ₂	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.05
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P ₁	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	8.00
Reel width	W ₁	1.0	12.30

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMAF	7"	3,000	4.0	6,000	210*208*203	178	400*265*400	120,000	10.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	1.8	0.071
B	1.6	0.063
C	3.8	0.150
D	2.2	0.087
E	5.4	0.213